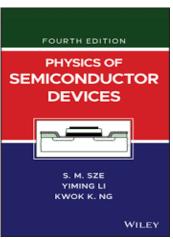




- Professor: 林崇榮 Chrong Jung Lin
- TA: TBD
- Course Handouts (download from EEClass)
- Reference Books
 - 1. Fundamentals of Semiconductor Devices (Ref.)
 by Betty L. Anderson & Richard L. Anderson
 - 2. Physics of Semiconductor Devices (Ref.) by Simon M. Sze, Yiming Li, Kwok K. N







Course Description

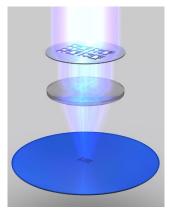
The course of "Introduction to Solid-State Electronic Devices" (固態電子元件導論) is a foundational course designed for undergraduate students who wish to acquire a comprehensive understanding of semiconductor devices, including their fundamental characteristics, mechanisms, and underlying physics. In this course, students will learn important topics such as semiconductor band theory, carrier transportation and conduction in semiconductors, semiconductor junctions and diodes, MOS capacitors, MOSFETs, bipolar transistors, as well as VLSI memory technologies. Additionally, this course incorporates contemporary knowledge on semiconductor devices, ensuring students stay up to date with the latest advancements in the semiconductor field.

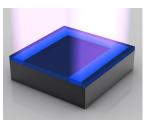
Expertise in Semiconductor

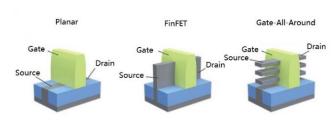
Manufacturing

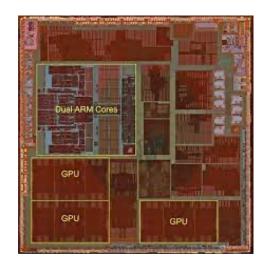
Technology

Chip Design





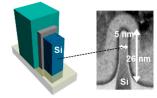


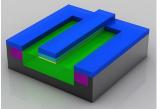


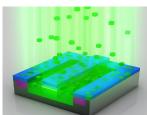
(a) GAA NW-FET

Si 8 nm









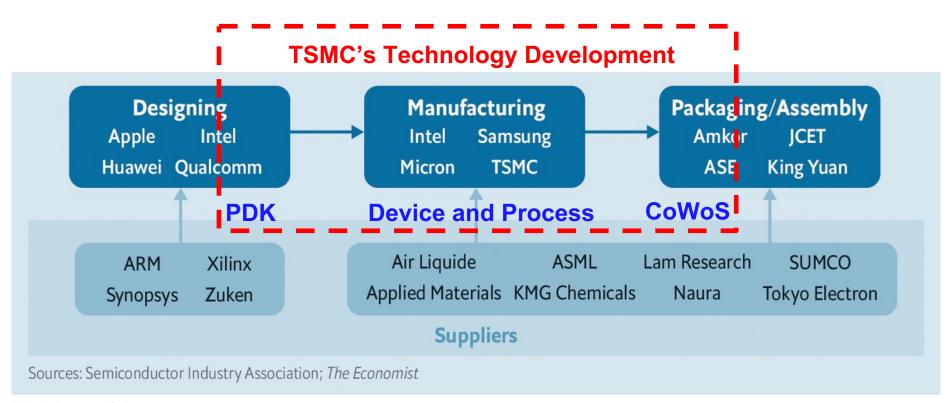
Solid-State Electronic Devices (固態電子元件)

VLSI Circuit / Memory Design (積體電路設計)

Process and Module
(Lithography/Etch/Thin Film/Diffusion)
(製程與微電子工程)

VLSI Device (積體電路元件) Digital/Analog Designs (數位類比電路設計)

Semiconductor Industry Chain



The Economist



Syllabus for 16 Weeks

- Chap 1: Semiconductor Energy States and Bands (2W)
- Chap 2: Carrier Concentration and Conduction (2.5W)
- Chap 3: Semiconductor Junction and Diodes (2.5W)
- Midterm Exam (1W)
- Chap 4: MOS Capacitor and Planar MOSFET (2.5W)
- Chap 5: SOI and 3D MOSFET Technologies (2.5W)
- Chap 6: Bipolar Junction Transistor BJT (2W)
- Final Exam (1W)



- 40% for Quiz or Homework
- 30% for Midterm Exam
- 30% for Final Exam